

TMC-2C43-016

InGaAs PIN photodiode TO-46 metal can

FEATURES:

- Industry standard TO-46 package with cap lens and tab-less.
- Optimized for fiber optic application.
- High responsivity at 1310nm and 1550nm.
- Low inter-modulation distortion.
- Suitable for CATV application.



ELECTRO-OPTICAL CHARACTERISTICS: (Typical values are at 25°C)

PARAMETERS	SYMBOL	MIN	TYP	MAX	UNIT	TEST CONDITIONS
Responsivity	R	0.8	0.9		A/W	$\lambda=1310\text{nm}$
		0.9	1.0			$\lambda=1550\text{nm}$
Dark Current	I_D		0.1	1	nA	$V_R=5\text{V}$, $T_A=25^\circ\text{C}$
Breakdown Voltage	V_{BD}	25	50		V	$I_R=10\mu\text{A}$
2 nd order Inter-modulation distortion	IMD2		-75	-70	dBc	$\lambda=1550\text{nm}^{(1)}$
3 rd order Inter-modulation distortion	IMD3		-85	-80	dBc	$\lambda=1550\text{nm}^{(2)}$
Capacitance	C		0.56	0.7	pF	$V_R=5\text{V}$, $f=1\text{MHz}$
Bandwidth	BW	2.5	3.2		GHz	$V_R=5\text{V}$

Notes:

1. IMD2 measured at $V_R=12\text{V}$, $P_{\text{avg}}=0\text{dBm}$, $\text{OMI}=0.7$, $R_{\text{LOAD}}=50\Omega$, $f_1+f_2=850\text{ MHz}$, $f_1-f_2=50\text{ MHz}$. All are measured at 25°C .
2. IMD3 measured at $V_R=12\text{V}$, $P_{\text{avg}}=0\text{dBm}$, $\text{OMI}=0.7$, $R_{\text{LOAD}}=50\Omega$, $2f_1-f_2=500\text{ MHz}$, $2f_2-f_1=350\text{ MHz}$. All are measured at 25°C .

ABSOLUTE MAXIMUM RATINGS:

PARAMETERS	MIN	MAX	UNIT	TEST CONDITIONS
Storage Temperature	-40	125	$^\circ\text{C}$	
Operating Temperature	-40	85	$^\circ\text{C}$	
Lead Solder Temperature		260	$^\circ\text{C}$	10 seconds
Forward current		10	mA	
Reverse voltage		20	V	

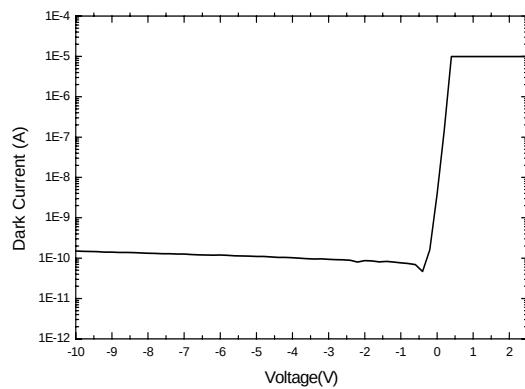


Fig. 1 Typical Dark Current and Forward Current.

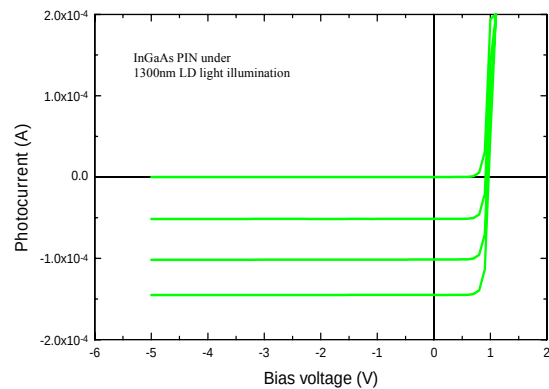


Fig. 2 Typical Photo-Current

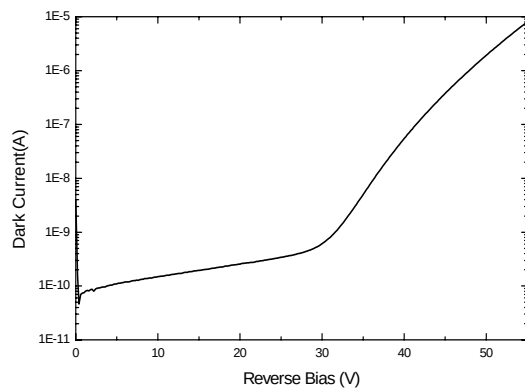


Fig. 3 Typical Breakdown Curve.

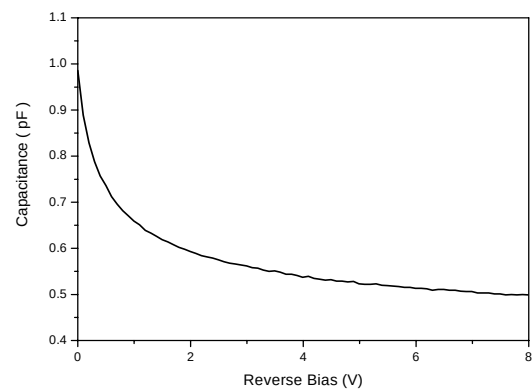
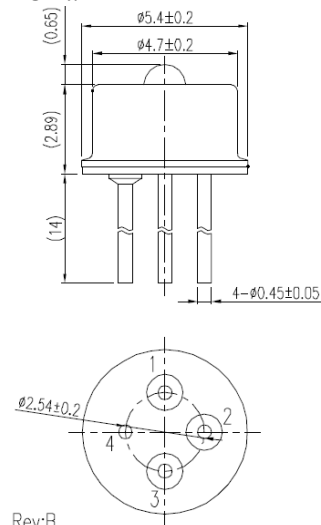


Fig. 4 Typical C-V Curve

OUTLINE DIMENSIONS:

• Unit: mm



Pinout:

1. Anode
2. N.C.
3. Cathode
4. Case